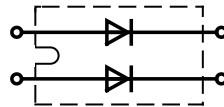


Fast Recovery Epitaxial Diode (FRED)

$I_{FAVM} = 2x\ 91\ A$
 $V_{RRM} = 1200\ V$
 $t_{rr} = 40\ ns$

V_{RSM}	V_{RRM}	Type
V	V	
1200	1200	DSEI 2x 101-12A


miniBLOC, SOT-227 B


E72873

Symbol	Test Conditions	Maximum Ratings (per diode)	
$I_{F(RMS)}$	$T_{VJ} = T_{VJM}$	130	A
$I_{F(AVM)}^{①}$	$T_C = 50^\circ C$; rectangular, $d = 0.5$	91	A
I_{FRM}	$t_P < 10\ \mu s$; rep. rating, pulse width limited by T_{VJM}	TBD	A
I_{FSM}	$T_{VJ} = 45^\circ C$; $t = 10\ ms$ (50 Hz), sine $t = 8.3\ ms$ (60 Hz), sine	900	A
		970	A
	$T_{VJ} = 150^\circ C$; $t = 10\ ms$ (50 Hz), sine $t = 8.3\ ms$ (60 Hz), sine	810	A
		870	A
I^2t	$T_{VJ} = 45^\circ C$; $t = 10\ ms$ (50 Hz), sine $t = 8.3\ ms$ (60 Hz), sine	4100	A ² s
		4000	A ² s
	$T_{VJ} = 150^\circ C$; $t = 10\ ms$ (50 Hz), sine $t = 8.3\ ms$ (60 Hz), sine	3300	A ² s
		3200	A ² s
T_{VJ}		-40...+150	°C
T_{VJM}		150	°C
T_{stg}		-40...+150	°C
P_{tot}	$T_C = 25^\circ C$	250	W
V_{ISOL}	50/60 Hz, RMS $I_{ISOL} \leq 1\ mA$	2500	V~
M_d	Mounting torque	1.5/13	Nm/lb.in.
	Terminal connection torque (M4)	1.5/13	Nm/lb.in.
Weight		30	g

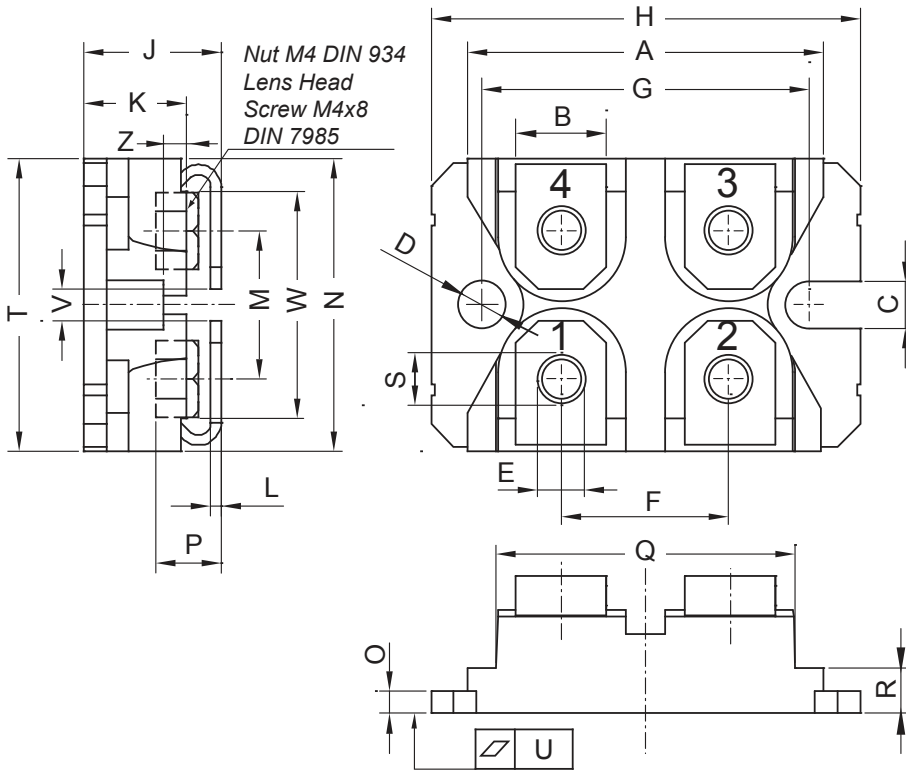
Features

- International standard package
- miniBLOC (ISOTOP compatible)
- Isolation voltage 2500 V~
- matched diodes f. parallel operation
- Planar passivated chips
- two independent diodes
- Very short recovery time
- Extremely low switching losses
- Low I_{RM} -values
- Soft recovery behaviour

Symbol	Test Conditions	Characteristic Values (per diode)	
		typ.	max.
I_R	$T_{VJ} = 25^\circ C$	$V_R = V_{RRM}$	3 mA
	$T_{VJ} = 25^\circ C$	$V_R = 0.8 \cdot V_{RRM}$	1.5 mA
	$T_{VJ} = 125^\circ C$	$V_R = 0.8 \cdot V_{RRM}$	15 mA
V_F	$I_F = 100\ A$; $T_{VJ} = 150^\circ C$ $T_{VJ} = 25^\circ C$		1.61 V
			1.87 V
V_{T0}	For power-loss calculations only		1.01 V
r_T			6.1 mΩ
R_{thJC} R_{thCH}		0.05	0.5 K/W
			K/W
t_{rr}	$I_F = 1\ A$; $-di/dt = 400\ A/\mu s$; $V_R = 30\ V$; $T_{VJ} = 25^\circ C$	40	60 ns
I_{RM}	$V_R = 100\ V$; $I_F = 75\ A$; $-di_F/dt = 200\ A/\mu s$ $L \leq 0.05\ mH$; $T_{VJ} = 100^\circ C$	24	30 A

① I_{FAVM} rating includes reverse blocking losses at T_{VJM} , $V_R = 0.8 V_{RRM}$, duty cycle $d = 0.5$
Data according to IEC 60747

miniBLOC, SOT-227 B



Dim.	Millimeter		Inches	
	min	max	min	max
A	31.50	31.88	1.240	1.255
B	7.80	8.20	0.307	0.323
C	4.09	4.29	0.161	0.169
D	4.09	4.29	0.161	0.169
E	4.09	4.29	0.161	0.169
F	14.91	15.11	0.587	0.595
G	30.12	30.30	1.186	1.193
H	37.80	38.23	1.488	1.505
J	11.68	12.22	0.460	0.481
K	8.92	9.60	0.351	0.378
L	0.74	0.84	0.029	0.033
M	12.50	13.10	0.492	0.516
N	25.15	25.42	0.990	1.001
O	1.95	2.13	0.077	0.084
P	4.95	6.20	0.195	0.244
Q	26.54	26.90	1.045	1.059
R	3.94	4.42	0.155	0.167
S	4.55	4.85	0.179	0.191
T	24.59	25.25	0.968	0.994
U	-0.05	0.10	-0.002	0.004
V	3.20	5.50	0.126	0.217
W	19.81	21.08	0.780	0.830
Z	2.50	2.70	0.098	0.106

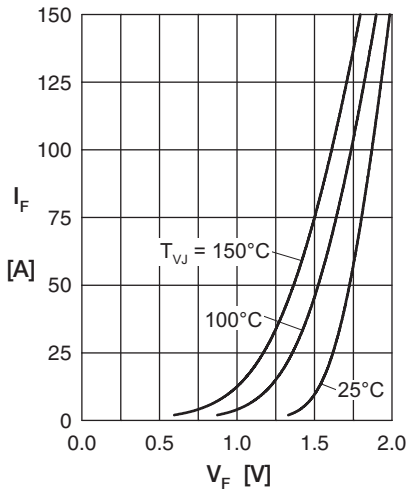


Fig. 1 Forward current I_F versus V_F

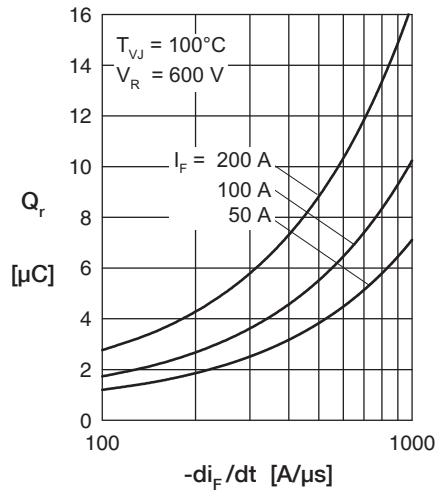


Fig. 2 Typ. reverse recov. charge Q_{rr} versus $-di_F/dt$

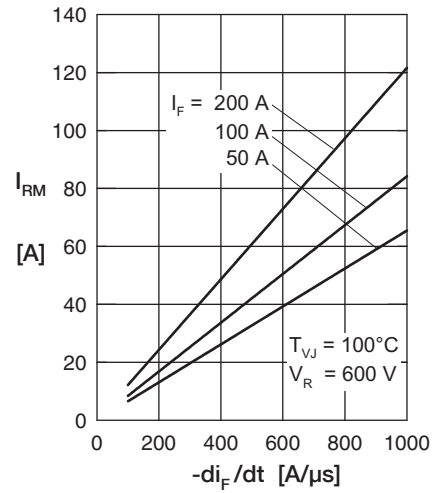


Fig. 3 Typ. peak reverse current I_{RM} versus $-di_F/dt$

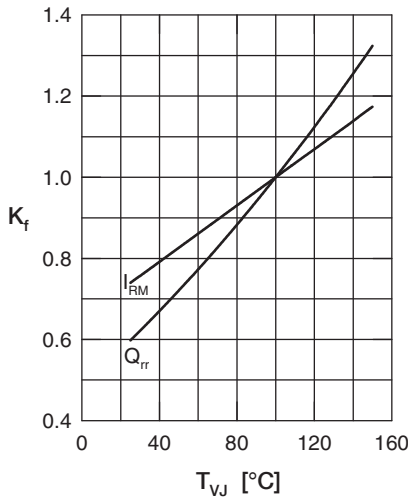


Fig. 4 Dyn. parameters Q_{rr} , I_{RM} versus T_{VJ}

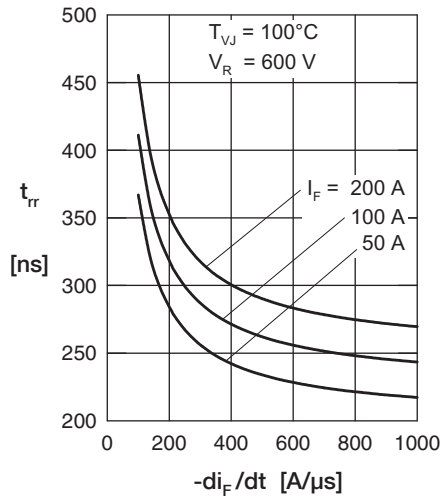


Fig. 5 Typ. recovery time t_{rr} versus $-di_F/dt$

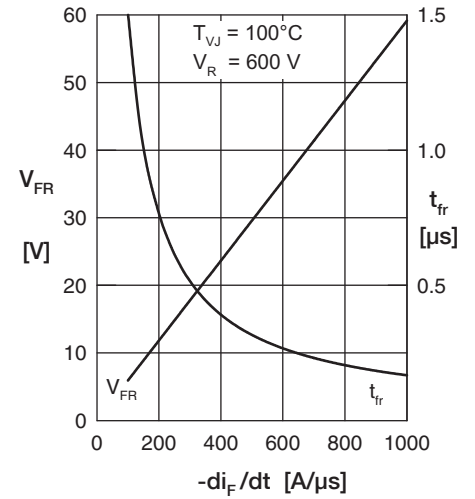


Fig. 6 Typ. peak forward voltage V_{FR} and t_{rr} versus di_F/dt

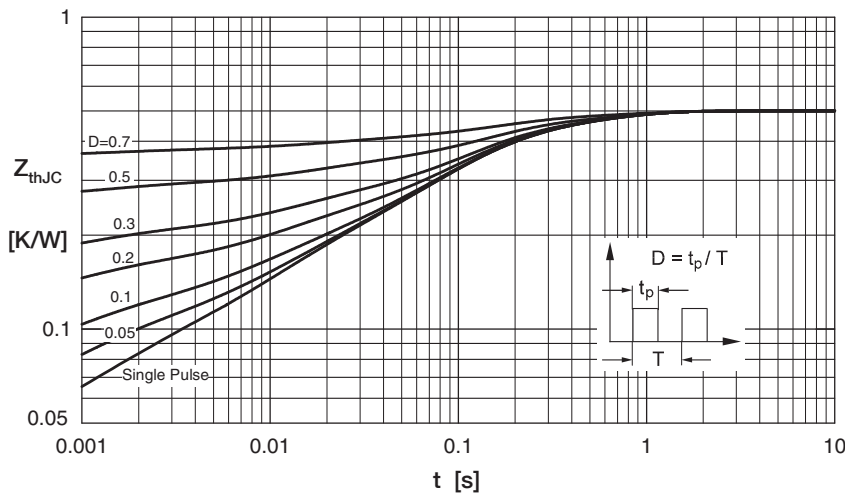


Fig. 7 Transient thermal impedance junction to case

Constants for Z_{thJC} calculation:

i	R_{thi} [K/W]	t_i [s]
1	0.0020	0.00002
2	0.0050	0.00081
3	0.0076	0.01
4	0.0240	0.94
5	0.0114	0.45